



100V PNP MEDIUM POWER TRANSISTOR IN PowerDI3333-8

Features

- BV_{CEO} > -100V
- Small Form Factor Thermally Efficient Package.
 Enables Higher Density End Products
- I_C = -2A High Continuous Current
- I_{CM} = -6A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -250mV @ -1A
- Complementary NPN Type: DXTN07100BFG
- Rated to +175°C Ideal For High Temperature Environment
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXTP07100BFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208 (£3)
- Weight: 0.03 grams (Approximate)

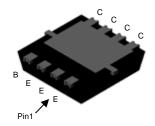
Applications

- High-Side Switch
- Low Drop Out Regulator
- MOSFET or IGBT Gate Driving

PowerDI3333-8 (SWP) (Type UX)

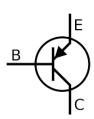


Top View



Bottom View

Equivalent Circuit



Device Symbol

Ordering Information (Note 4)

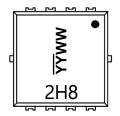
Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTP07100BFGQ-7	Automotive	2H8	7	12	2,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information

PowerDI3333-8 (SWP) (Type UX)



2H8= Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 21 = 2021)

WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Absolute Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	-120	V
Collector-Emitter Voltage	Vceo	-100	V
Emitter-Base Voltage	VEBO	-7	V
Continuous Collector Current	Ic	-2	Α
Peak Pulse Current	Ісм	-6	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		1.1	W
Power Dissipation	(Note 6)	PD	2.3	W
	(Note 7)		3.4	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	65	°C/W
	(Note 7)		44	°C/W
Thermal Resistance, Junction to Leads (Note 8	RøJL	8.5	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

ESD Ratings (Note 9)

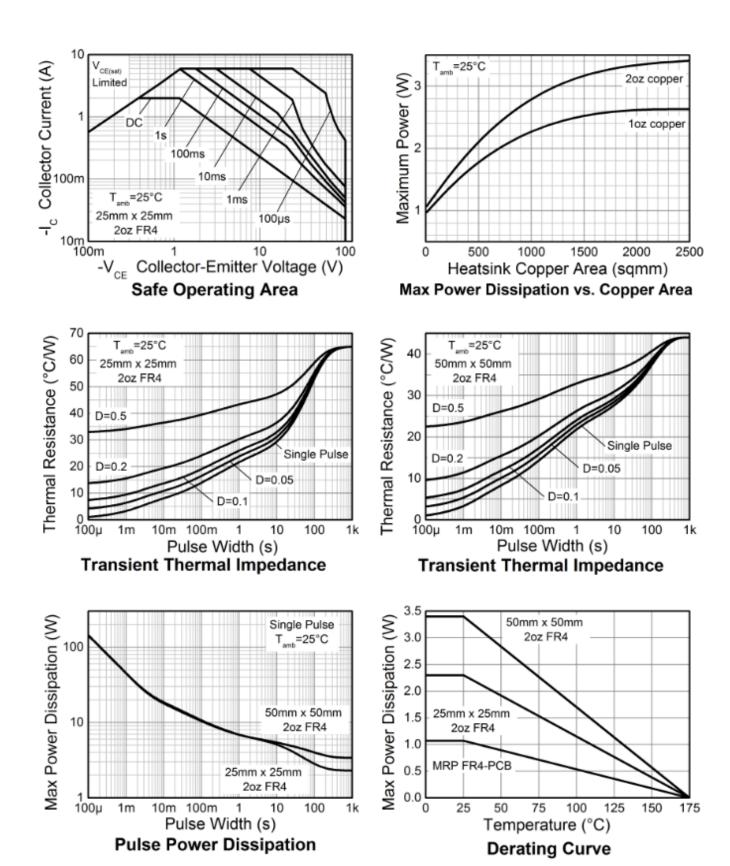
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper. 7. Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
- 8. Thermal resistance from junction to solder-point (at the collector tab).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





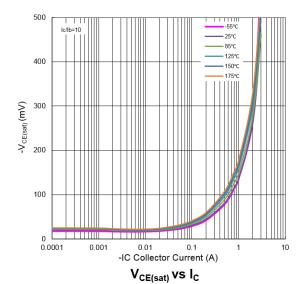
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

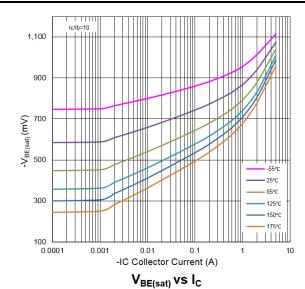
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	-120	-170	_	V	Ic = -100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-100	-124	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.4	_	V	I _E = -100μA
Collector Cut-Off Current		_	_	-50	nA	V _{CB} = -100V
Collector Cut-Oil Current	Ісво	_	_	-10	μΑ	V _{CB} = -100V, T _A = +125°C
Emitter Cut-Off Current	I _{EBO}	_	_	-20	nA	V _{EB} = -6V
Collector Emitter Caturation Valtage (Note 10)	V	_	-137	-250	mV	Ic = -1A, I _B = -100mA
Collector-Emitter Saturation Voltage (Note 10)	VCE(sat)	_	-260	-500	mV	Ic = -2A, I _B = -200mA
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	_	-0.87	-1	V	Ic = -1A, I _B = -100mA
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	_	-0.78	-0.95	V	I _C = -1A, V _{CE} = -2V
	hFE	70	177	_	_	Ic = -50mA, VcE = -2V
DC Current Coin (Note 10)		100	161	300	_	Ic = -500mA, VcE = -2V
DC Current Gain (Note 10)		55	146	_	_	$I_{C} = -1A$, $V_{CE} = -2V$
		25	53	_	_	Ic = -2A, VcE = -2V
Current Gain-Bandwidth Product	fτ	100	140	_	MHz	$V_{CE} = -5V$, $I_{C} = -100$ mA f = 100MHz
Turn-On Time	ton	_	40	_	ns	Vcc = -10V, Ic = -500mA
Turn-Off Time	t _{off}	_	600	_	ns	I _{B1} = -I _{B2} = -50mA
Output Capacitance	C _{obo}	_	_	30	pF	V _{CB} = -10V, f = 1MHz

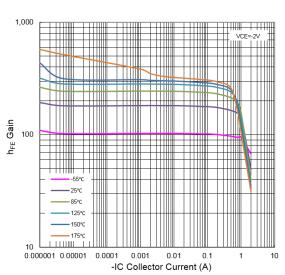
Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



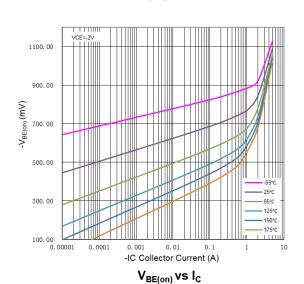
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

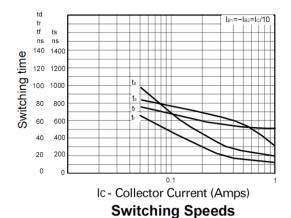






 $h_{\text{FE}} \text{ vs } I_{\text{C}}$



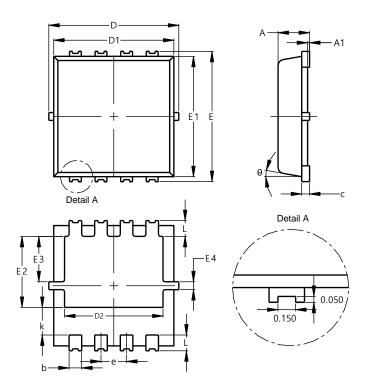




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

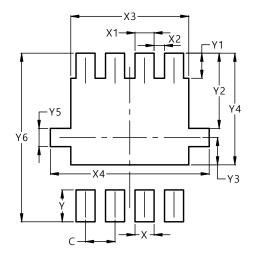


PowerDI3333-8 (SWP)					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е	_	_	0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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